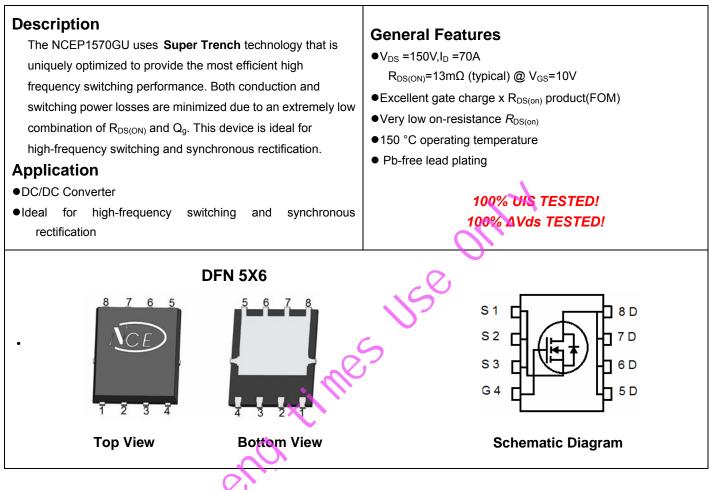


NCE N-Channel Super Trench Power MOSFET



Package Marking and Ordering Information

| Device Marking | Device | Device Package | Reel Size | Tape width | Quantity |
|----------------|------------|----------------|-----------|------------|----------|
| P1570GU | NCEP1570GU | DFN5X6-8L | - | - | - |

Absolute Maximum Ratings (T_A=25℃unless otherwise noted)

| Parameter | Symbol | Limit | Unit |
|--|----------------------------------|------------|------|
| Drain-Source Voltage | V _{DS} | 150 | V |
| Gate-Source Voltage | V _{GS} | ±20 | V |
| Drain Current-Continuous | Ι _D | 70 | А |
| Drain Current-Continuous(T _C =100°C) | I _D (100℃) | 49.5 | A |
| Pulsed Drain Current | I _{DM} | 280 | А |
| Maximum Power Dissipation | PD | 150 | W |
| Derating factor | | 1.2 | W/℃ |
| Single pulse avalanche energy (Note 5) | E _{AS} | 583 | mJ |
| Operating Junction and Storage Temperature Range | T _J ,T _{STG} | -55 To 150 | °C |

Thermal Characteristic

| Thermal Résistance, Junction-to-Case ^(Note 2) | $R_{	extsf{	heta}JC}$ | 0.83 | °C/W |
|--|-----------------------|------|------|
|--|-----------------------|------|------|



Electrical Characteristics (T_A=25°C unless otherwise noted)

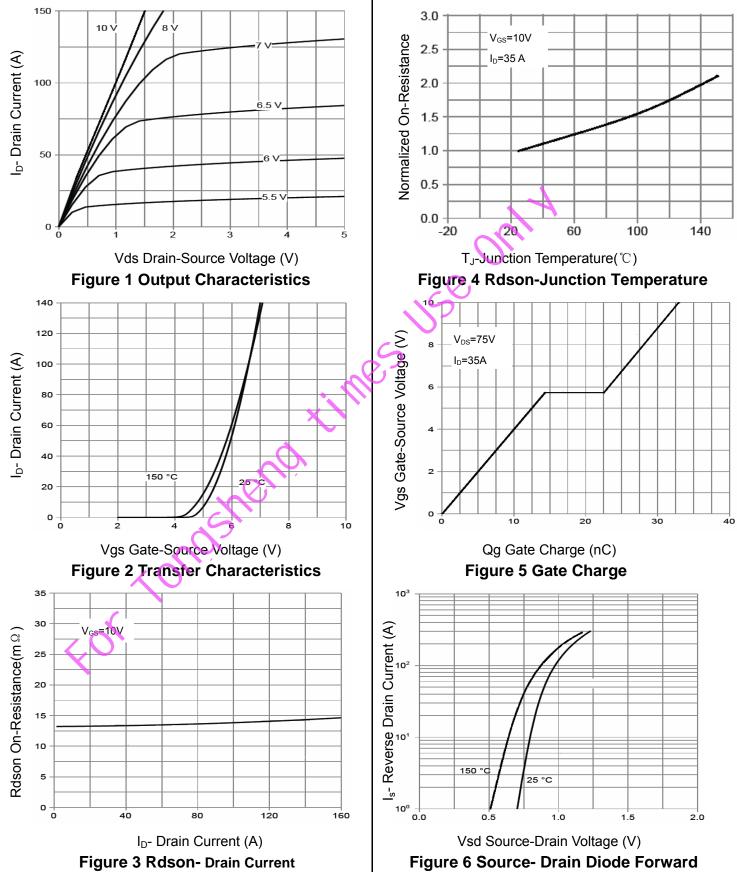
| Parameter | Symbol | Condition | Min | Тур | Max | Unit |
|------------------------------------|-----------------------|---|-----|------|------|------|
| Off Characteristics | | | | | | |
| Drain-Source Breakdown Voltage | BV _{DSS} | V _{GS} =0V I _D =250µA | 150 | - | - | V |
| Zero Gate Voltage Drain Current | I _{DSS} | V _{DS} =150V,V _{GS} =0V | - | - | 1 | μA |
| Gate-Body Leakage Current | I _{GSS} | $V_{GS}=\pm 20V, V_{DS}=0V$ | - | - | ±100 | nA |
| On Characteristics (Note 3) | | | | | | |
| Gate Threshold Voltage | V _{GS(th)} | $V_{DS}=V_{GS}$, $I_{D}=250\mu A$ | 2.0 | | 4.0 | V |
| Drain-Source On-State Resistance | R _{DS(ON)} | V_{GS} =10V, I _D =35A | - | 13 | 15 | mΩ |
| Forward Transconductance | g fs | V _{DS} =5V,I _D =35A | - | 58 | - | S |
| Dynamic Characteristics (Note4) | | | 1 | | | |
| Input Capacitance | C _{lss} | | | 2200 | - | PF |
| Output Capacitance | C _{oss} | V _{DS} =75V,V _{GS} =0V, F=1.0MHz | - | 289 | - | PF |
| Reverse Transfer Capacitance | C _{rss} | | - | 11.2 | - | PF |
| Switching Characteristics (Note 4) | | 0, | | | | |
| Turn-on Delay Time | t _{d(on)} | 15 | - | 12.5 | - | nS |
| Turn-on Rise Time | tr | V _{DD} =75V, I _D =35A | - | 3.8 | - | nS |
| Turn-Off Delay Time | t _{d(off)} | V_{GS} =10V, R_{G} =3 Ω | - | 14 | - | nS |
| Turn-Off Fall Time | t _f | | - | 3.5 | - | nS |
| Total Gate Charge | Q _g | V -75V/1 -25A | - | 33 | - | nC |
| Gate-Source Charge | Q _{g\$} | V _{DS} =75V,I _D =35A, V _{GS} =10V | - | 14.5 | - | nC |
| Gate-Drain Charge | Q _{gd} | V _{GS} -10V | - | 8 | - | nC |
| Drain-Source Diode Characteristics | $\boldsymbol{\wedge}$ | | | | | |
| Diode Forward Voltage (Note 3) | V _{SD} | V _{GS} =0V,I _S =35A | - | - | 1.2 | V |
| Diode Forward Current (Note 2) | I _S | | - | - | 70 | А |
| Reverse Recovery Time | t _{rr} | $T_J = 25^{\circ}C, I_F = 35A$ | - | 47 | - | nS |
| Reverse Recovery Charge | Qrr | di/dt = $100A/\mu s^{(Note3)}$ | - | 55 | - | nC |
| Fortour | | | | | | |

Notes:

- 1. Repetitive Rating: Pulse width limited by maximum junction temperature.
- 2. Surface Mounted on FR4 Board, t \leq 10 sec. The value of R_{0JA} is measured with the device mounted on 1in² FR-4 board with 2oz. Copper, in a still air environment with T_A =25° C. the maximum allowed junction temperature of 150°C. The value in any given application depends on the user's specific board design.
- 3. Pulse Test: Pulse Width ≤ 300 μ s, Duty Cycle ≤ 2%.
- 4. Guaranteed by design, not subject to production
- 5. E_{AS} condition : Tj=25 °C, V_{DD}=50V, V_G=10V, L=0.5mH, Rg=25\Omega



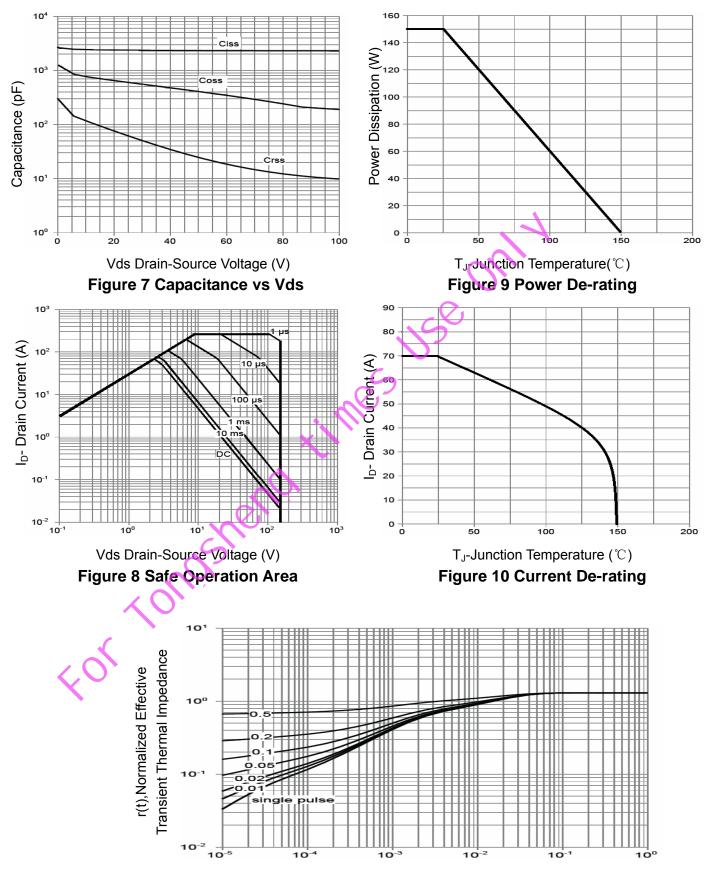






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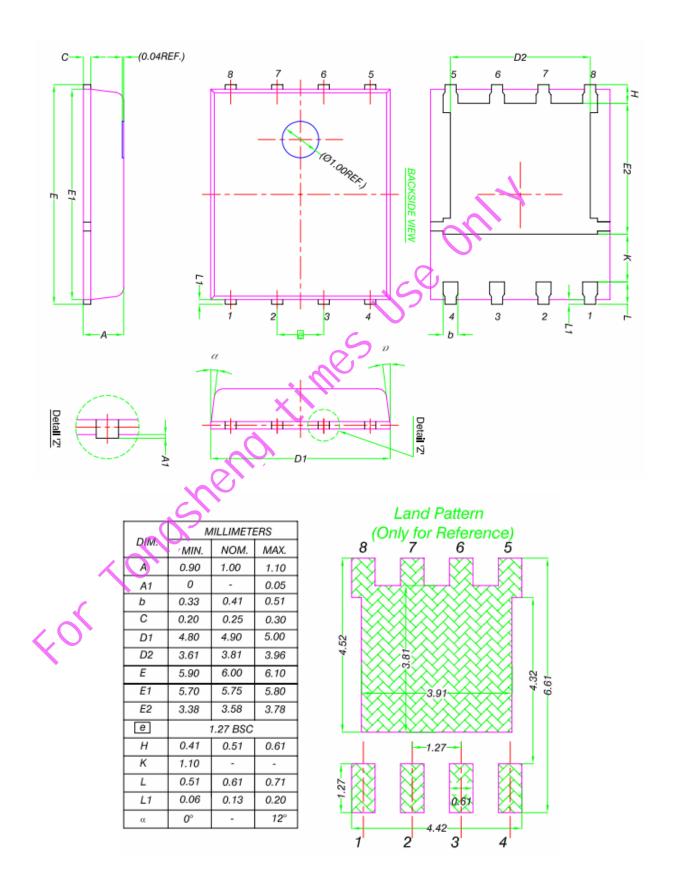
NCEP1570GU



Square Wave Pluse Duration(sec) Figure 11 Normalized Maximum Transient Thermal Impedance



DFN5X6-8L Package Information





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